

Low voltage PNP power transistor

Features

- This device is qualified for automotive application
- Surface-mounting TO-252 power package in tape and reel
- Complementary to the NPN type MJD31C

Application

- General purpose linear and switching equipment

Description

The device is manufactured in planar technology with “base island” layout. The resulting transistor shows exceptional high gain performance coupled with very low saturation voltage.

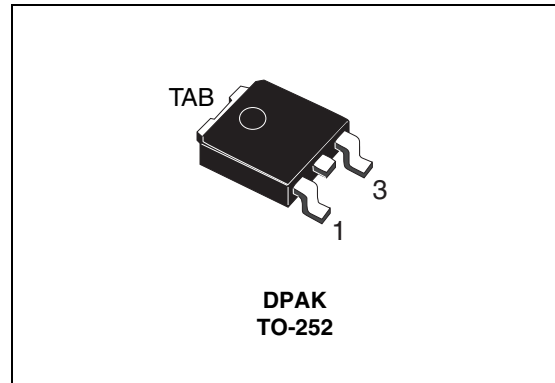


Figure 1. Internal schematic diagram

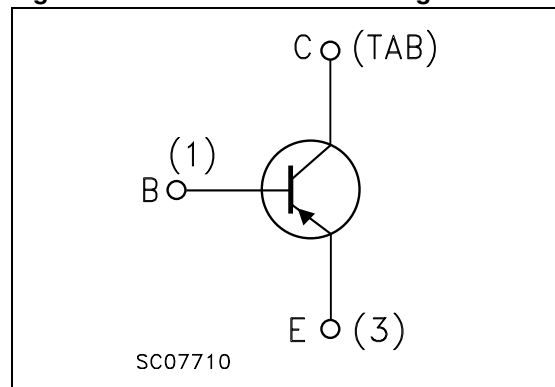


Table 1. Device summary

Order code	Marking	Package	Packaging
MJD32CT4-A	MJD32C	DPAK	Tape and reel

1 Electrical ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V_{CBO}	Collector-base voltage ($I_E = 0$)	-100	V
V_{CEO}	Collector-emitter voltage ($I_B = 0$)	-100	V
V_{EBO}	Emitter-base voltage ($I_C = 0$)	-5	V
I_C	Collector current	-3	A
I_{CM}	Collector peak current	-5	A
I_B	Base current	-1	A
P_{TOT}	Total dissipation at $T_c = 25\text{ °C}$	15	W
T_{STG}	Storage temperature	-65 to 150	°C
T_J	Max. operating junction temperature	150	°C

Table 3. Thermal data

Symbol	Parameter	Value	Unit
R_{thJC}	Thermal resistance junction-case	Max 8.3	°C/W
$R_{thJP}^{(1)}$	Thermal resistance junction-pcb	Max 50	°C/W

1. When mounted on FR-4 board of 1 inch², 2 oz Cu.

2 Electrical characteristics

$T_{case} = 25\text{ }^{\circ}\text{C}$ unless otherwise specified.

Table 4. Electrical characteristics

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
I_{CES}	Collector cut-off current ($V_{BE} = 0$)	$V_{CE} = -100\text{ V}$		-	-20	μA
I_{CEO}	Collector cut-off current ($I_B = 0$)	$V_{CB} = -60\text{ V}$		-	-50	μA
I_{EBO}	Emitter cut-off current ($I_C = 0$)	$V_{EB} = -5\text{ V}$		-	-0.1	mA
$V_{CEO(sus)}^{(1)}$	Collector-emitter sustaining voltage ($I_B = 0$)	$I_C = -30\text{ mA}$	-100	-		V
$V_{CE(sat)}^{(1)}$	Collector-emitter saturation voltage	$I_C = -3\text{ A}$ $I_B = -375\text{ mA}$		-	-1.2	V
$V_{BE(on)}^{(1)}$	Base-emitter on voltage	$I_C = -3\text{ A}$ $V_{CE} = -4\text{ V}$		-	-1.8	V
h_{FE}	DC current gain	$I_C = -1\text{ A}$ $V_{CE} = -4\text{ V}$ $I_C = -3\text{ A}$ $V_{CE} = -4\text{ V}$	25 10	-	50	

1. Pulse test: pulse duration $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$

2.1 Electrical characteristic (curves)

Figure 2. Safe operating area

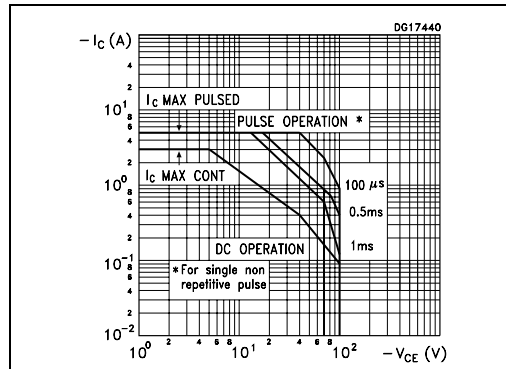


Figure 3. Derating curve

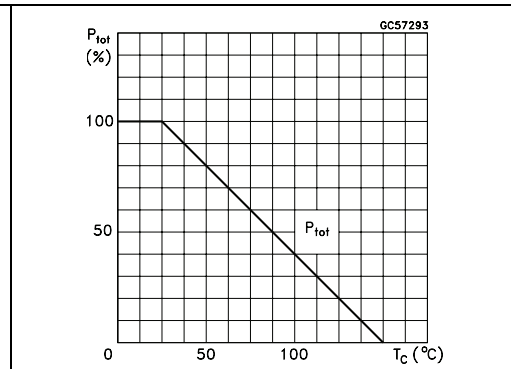


Figure 4. DC current gain ($V_{CE} = -2\text{ V}$) Figure 5. DC current gain ($V_{CE} = -4\text{ V}$)

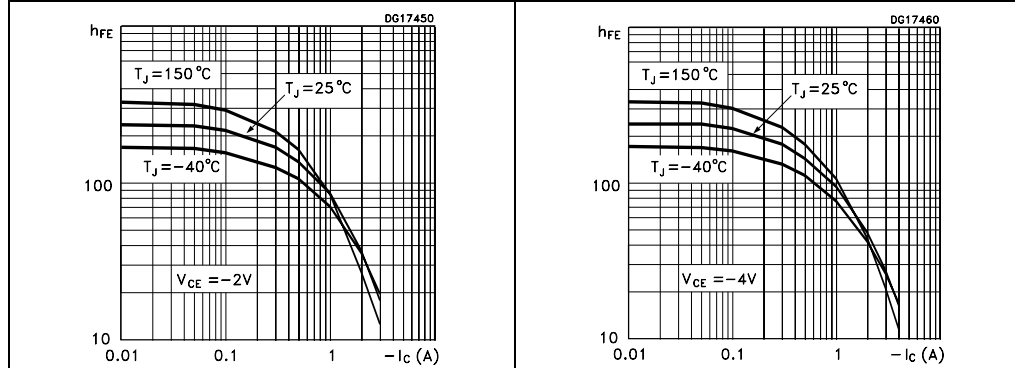


Figure 6. Collector-emitter saturation voltage Figure 7. Base-emitter saturation voltage

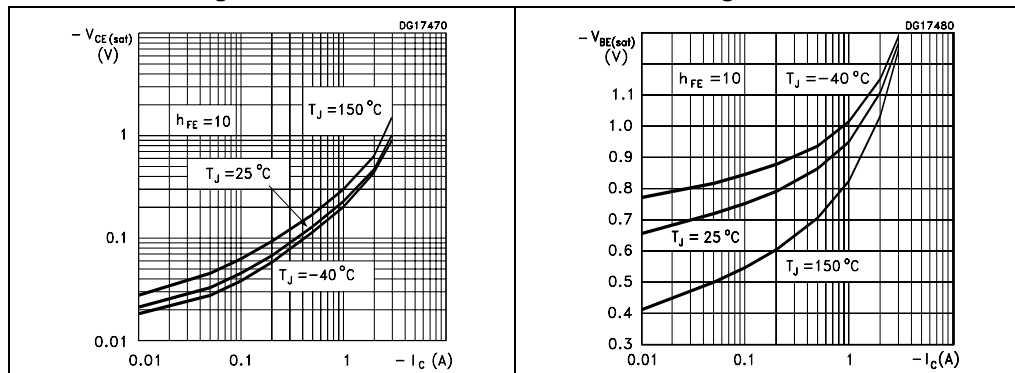


Figure 8. Base-emitter on voltage Figure 9. Resistive load switching time (on)

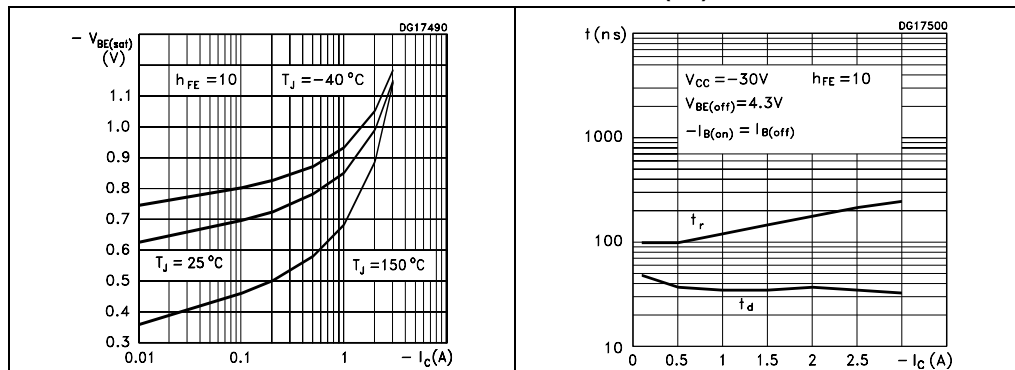
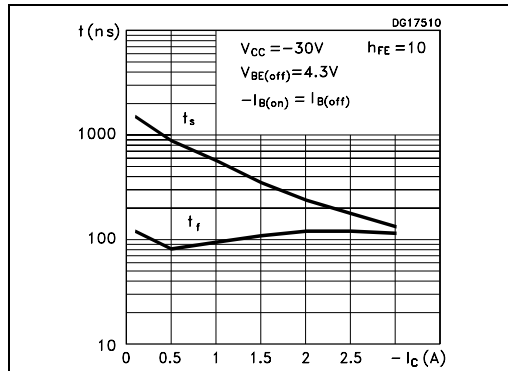
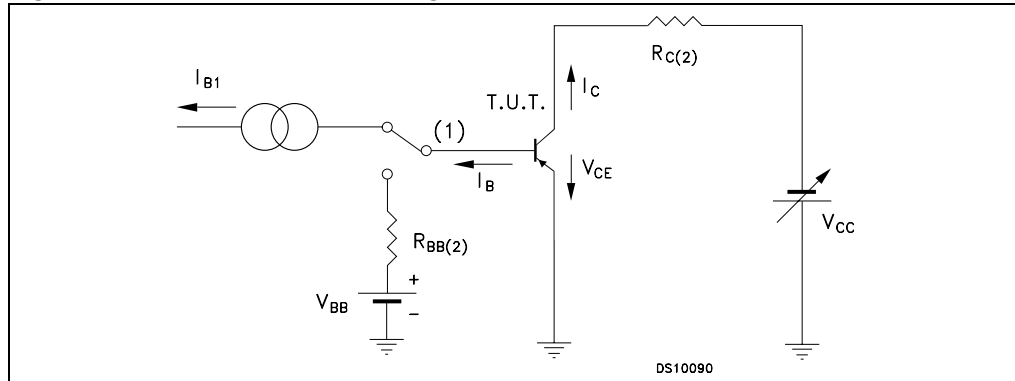


Figure 10. Resistive load switching time (off)



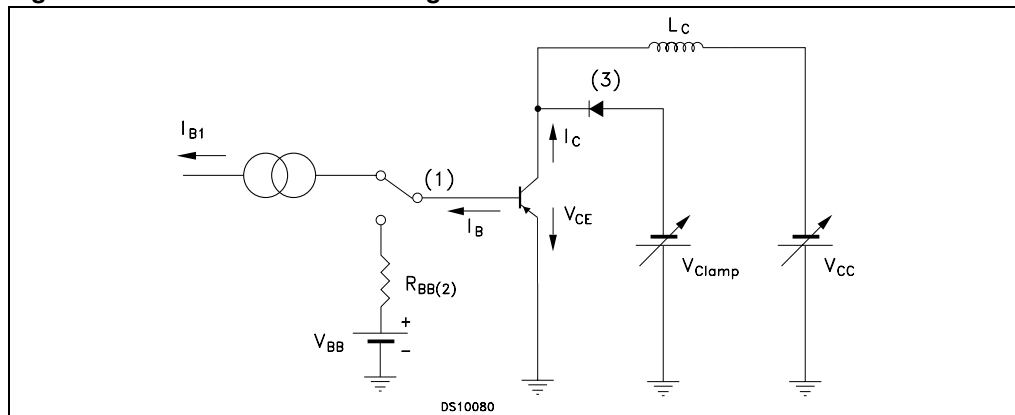
2.2 Test circuits

Figure 11. Resistive load switching test circuit



1. Fast electronic switch
2. Non-inductive resistor

Figure 12. Inductive load switching test circuit



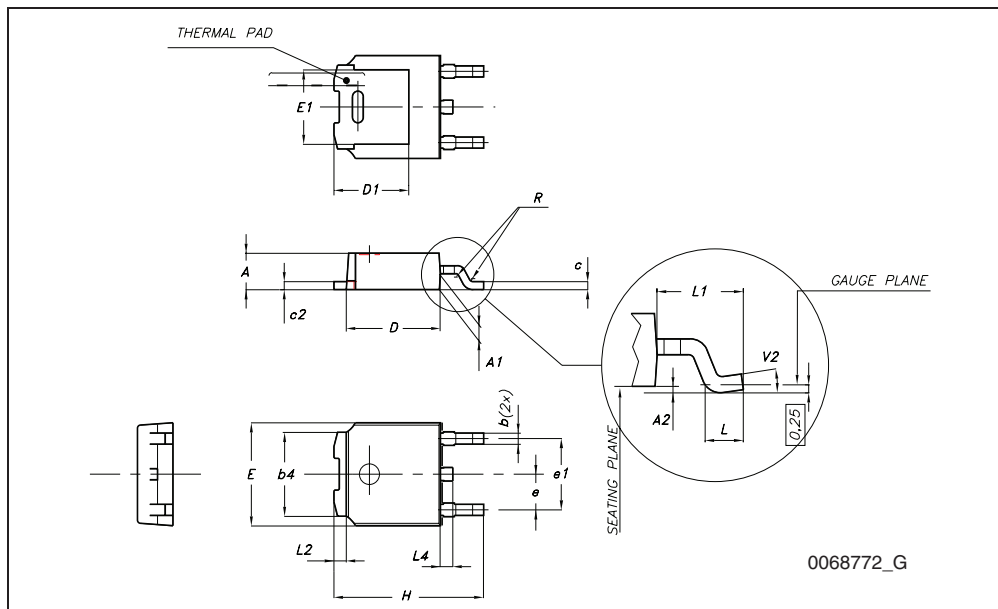
1. Fast electronic switch
2. Non-inductive resistor
3. Fast recovery rectifier

3 Package mechanical data

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TO-252 (DPAK) mechanical data

DIM.	mm.		
	min.	typ	max.
A	2.20		2.40
A1	0.90		1.10
A2	0.03		0.23
b	0.64		0.90
b4	5.20		5.40
c	0.45		0.60
c2	0.48		0.60
D	6.00		6.20
D1		5.10	
E	6.40		6.60
E1		4.70	
e		2.28	
e1	4.40		4.60
H	9.35		10.10
L	1		
L1		2.80	
L2		0.80	
L4	0.60		1
R		0.20	
V2	0°		8°



4 Revision history

Table 5. Document revision history

Date	Revision	Changes
01-Jun-2007	1	Initial release.
09-Nov-2009	2	Updated package mechanical data.
14-Jan-2010	3	Modified Table 3 on page 2 .

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